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> Supplementary Information For Journal of Materials Chemistry A

## Synergistic Effect of Two Hydrochlorides Boosting 3D to

## **Quasi-2D Tin-Based Perovskite Solar Cells with**

## **Significantly Enhanced Performance**

Tianhao Li<sup>a#</sup>, Yangyang Wang<sup>a#</sup>, Weiya Zhu<sup>b</sup>, Qianxi Dang<sup>a</sup>, Yiheng Zhang<sup>b</sup>, Yuan Li<sup>b\*</sup> and Xianyu Deng<sup>a\*</sup>

<sup>a</sup> Shenzhen Key Laboratory of Advanced Materials, School of Materials Science and Engineering, Harbin Institute of Technology, Shenzhen, China.

Email: xydeng@hit.edu.cn

<sup>b</sup> State Key Laboratory of Luminescent Materials and Devices, Institute of Polymer Optoelectronic Materials and Devices, South China University of Technology, 381, Wushan Road, Guangzhou, 510641, China.

E-mail: celiy@scut.edu.cn

<sup>#</sup>T.L. and W. Y.Y. contributed equally to this work.



**Fig. S1.** (a) The progress of the Sn-based perovskite film via a one-step spin-coating method with antisolvent dripping. (b) Device structure of the 2D Sn-based PVSCs.



**Fig. S2.** Image of the precursor solution with different additives exposed in air for different time (the solution on the bottle wall can be considered as a mark to prove that the bottle has not moved during the shooting). The solution were marked as Sample 1: control solution; Sample 2: solution with DEACl; Sample 3: solution with HMCl; Sample 4: solution with HMCl and DEACl.



**Fig. S3.** Images of  $FASnI_3$  solution. (a)  $FASnI_3$  solution added with  $SnF_2$ . (b) solution exposed in air for 4 h. Add DEAC1 to the oxidized precursor solution and shake for (c) 10 s and (d) 1 min.



**Fig. S4.** Images of FASnI<sub>3</sub> solution. (a) The FASnI<sub>3</sub> solution added with  $SnF_2$ . (b) The solution exposed in air for 4 h. The oxidized precursor solution after adding HMCl and shaking for (c) 10 s and (d) 1 min.



**Fig. S5.** 3D schematic diagram of the transformation of FASnI<sub>3</sub> crystal in air environment.



**Fig. S6.** XPS Sn 3d spectra of corresponding films (a) without additives, (b) with addition of 20% HMCl, and (c) with addition of 20% HMCl and 20% DEACl. The two peaks deconvoluted from the measured spectra at 486.5 and 487.5 eV are associated with  $Sn^{2+}$  and  $Sn^{4+}$ , respectively. The etching time is 30 s.



**Fig. S7.** SEM images of the Sn-based perovskite films with different amounts of HMCl. (a) without HMCl. (b) with 10% HMCl added. (c) with 20% HMCl added. (d) with 30% HMCl added. (e) XRD patterns of the Sn-based films, the control film (FASnI<sub>3</sub> film with 0.1M SnF<sub>2</sub>), and the film with 0.2M HMCl added. (f) *J-V* curves of Sn-based devices containing different amounts of HMCl.



**Fig. S8.** (a) Absorption spectrum of the different films. (b) Tauc plot of Sn-based perovskite films with different additive (Photo energy are 1.33eV, 1.36 eV, 1.42 eV, respectively).



Fig. S9. J-V curves of Sn-based devices with and without DEACl.



Fig. S10. *J-V* curves of Sn-based devices containing HMCl with different large cations additive.



**Fig. S11.** (a) Dark *J-V* curves of the control, with addition of HMCl, and with addition of HMCl and DEACl devices (b)  $J_{SC}$ -*T* curves of the device with different additives under 1.5 G irradiation.

Year	Structure	Author	Journal	PCE (%)
2017	2D based $BA^+$	Mercouri G. Kanatzidis	ACS Energy Lett.	2.37
2017	2D based PEA <sup>+</sup>	Zhijun Ning	JACS	5.94
2018	2D-3D hybrid	Maria Antonietta Loi	Adv. Energy Mater.	9
2018	2D-3D hybrid	Zhijun Ning	Joule	9.41
2019	2D based AVA $^+$	Mingjian Yuan	Adv. Funct. Mater.	8.71
2020	2D based $BA^+$	Mingzhen Liu	ACS Energy Lett.	4.04
2021	3D	Zhijun Ning	J. Am. Chem. Soc	14.6
2021	2D-3D	Zhubing He	Adv. Mater.	14.8
2022	2D based $DEA^+$	This work		9.47

Table S1. The development of 2D tin-based perovskites in recent years

 Table S2. Device parameters of Sn-based perovskite films adding with different content HMCl.

Sample	$J_{SC}$ (mA/cm <sup>2</sup> )	$V_{OC}(\mathbf{V})$	FF (%)	PCE (%)
Control	15.3	0.31	48.28	2.29
10% HMCl	21.6	0.362	62.02	4.85
20% HMCl	22.7	0.396	66.22	5.95
30% HMCl	20.11	0.378	61.30	4.66

Table S3. Fitted TRPL parameters of Sn-based perovskite film with different additives.

Sample	$\tau_1$ (ns)	$\tau_2(ns)$
Control	2.14	7.43
With HMCl	5.21	9.67
With HMC1&DEAC1	7.92	16.32

 Table S4. Device parameters of Sn-based perovskite solar cells with and without adding DEACl.

Sample	$J_{SC}$ (mA/cm <sup>2</sup> )	$V_{OC}(\mathbf{V})$	FF (%)	PCE (%)
Control	15.3	0.31	48.28	2.29
With DEACl	14.39	0.493	51.71	3.67

**Table S5.** The corresponding parameters of trap concentration and carrier mobility of perovskite films with different additives.

Sample	$V_{TFL}(\mathbf{V})$	$N_{trap}$ (cm <sup>-3</sup> )	$\mu ({ m cm}^{-2}{ m V}^{-1}{ m S}^{-1})$
Control Film	0.321	6.44×10 <sup>15</sup>	1.2524×10 <sup>-4</sup>
With HMCl	0.0912	$1.242 \times 10^{15}$	1.0043×10 <sup>-3</sup>
With HMCl&DEACl	0.0644	1.126×10 <sup>15</sup>	4.4581×10 <sup>-3</sup>

**Table S6.** The electrostatic potential (ESP) parameters of DEA<sup>+</sup>, BA<sup>+</sup> and PEA<sup>+</sup> calculated by density functional theory (EFT).

Sample	MPI (eV)	Volume (Å)	Minima ESP (eV)	Maxima ESP
				(ev)
$DEA^+$	4.61911	123.61614	3.571654	6.511710
$BA^+$	4.46498	123. 81487	2.477844	6.933499
PEA <sup>+</sup>	3.86253	173.53287	1.907838	6.851608